

## Vishay Semiconductors

## Silicon Photodiode



#### **DESCRIPTION**

BPW21R is a planar Silicon PN photodiode in a hermetically sealed short TO-5 case, especially designed for high precision linear applications.

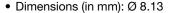
Due to its extremely high dark resistance, the short circuit photocurrent is linear over seven decades of illumination level.

On the other hand, there is a strictly logarithmic correlation between open circuit voltage and illumination over the same range.

The device is equipped with a flat glass window with built in color correction filter, giving an approximation to the spectral response of the human eye.

### **FEATURES**

Package type: leadedPackage form: TO-5



• Radiant sensitive area (in mm<sup>2</sup>): 7.5

· High photo sensitivity

· Adapted to human eye responsivity

• Angle of half sensitivity:  $\phi = \pm 50^{\circ}$ 

· Hermetically sealed package

· Cathode connected to package

· Flat glass window

· Low dark current

• High shunt resistance

· High linearity

 Compliant to RoHS Directive 2002/95/EC and in accordance with WEEE 2002/96/EC

#### **APPLICATIONS**

· Sensor in exposure and color measuring purposes

PRODUCT SUMMARY			
COMPONENT	I <sub>ra</sub> (μΑ)	φ (deg)	λ <sub>0.5</sub> (nm)
BPW21R	9	± 50	420 to 675

### Note

• Test condition see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
BPW21R	Bulk	MOQ: 500 pcs, 500 pcs/bulk	TO-5	

## Note

· MOQ: minimum order quantity

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V <sub>R</sub>	10	V	
Power dissipation	T <sub>amb</sub> ≤ 50 °C	P <sub>V</sub>	300	mW	
Junction temperature		Tj	125	°C	
Operating temperature range		T <sub>amb</sub>	- 40 to + 125	°C	
Storage temperature range		T <sub>stg</sub>	- 40 to + 125	°C	
Soldering temperature	t ≤ 5 s	T <sub>sd</sub>	260	°C	
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm <sup>2</sup>	R <sub>thJA</sub>	250	K/W	



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PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I <sub>F</sub> = 50 mA	$V_{F}$		1.0	1.3	V
Breakdown voltage	I <sub>R</sub> = 20 μA, E = 0	V <sub>(BR)</sub>	10			V
Reverse dark current	V <sub>R</sub> = 5 V, E = 0	I <sub>ro</sub>		2	30	nA
Diada assasitassa	V <sub>R</sub> = 0 V, f = 1 MHz, E = 0	C <sub>D</sub>		1.2		nF
Diode capacitance	$V_R = 5 \text{ V, } f = 1 \text{ MHz, } E = 0$	C <sub>D</sub>		400		pF
Dark resistance	V <sub>R</sub> = 10 mV	$R_D$		38		GΩ
Open circuit voltage	E <sub>A</sub> = 1 klx	Vo	280	450		mV
Temperature coefficient of Vo	E <sub>A</sub> = 1 klx	TK <sub>Vo</sub>		- 2		mV/K
Short circuit current	E <sub>A</sub> = 1 klx	l <sub>k</sub>	4.5	9		μΑ
Temperature coefficient of I <sub>K</sub>	E <sub>A</sub> = 1 klx	TK <sub>lk</sub>		- 0.05		%/K
Reverse light current	$E_A = 1 \text{ klx}, V_R = 5 \text{ V}$	I <sub>ra</sub>	4.5	9		μΑ
Sensitivity	$V_R = 5 \text{ V}, E_A = 10^{-2} \text{ to } 10^5 \text{ lx}$	S		9		nA/lx
Angle of half sensitivity		φ		± 50		deg
Wavelength of peak sensitivity		$\lambda_{p}$		565		nm
Range of spectral bandwidth		λ <sub>0.5</sub>		420 to 675		nm
Rise time	$V_R = 0 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 660 \text{ nm}$	t <sub>r</sub>		3.1		μs
Fall time	$V_{R} = 0 \text{ V}, R_{L} = 1 \text{ k}\Omega, \lambda = 660 \text{ nm}$	t <sub>f</sub>		3.0		μs

## **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

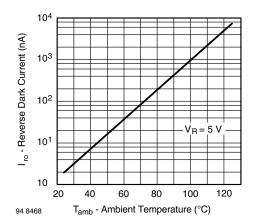


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

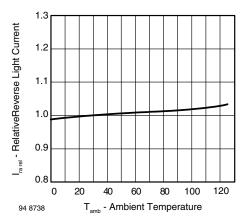


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature



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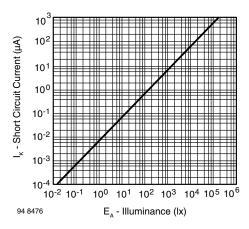


Fig. 3 - Short Circuit Current vs. Illuminance

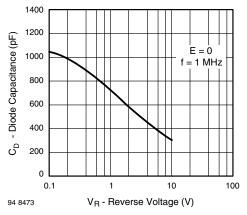


Fig. 4 - Diode Capacitance vs. Reverse Voltage

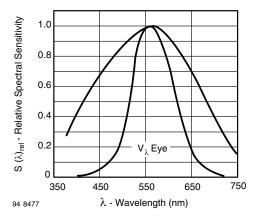


Fig. 5 - Relative Spectral Sensitivity vs. Wavelength

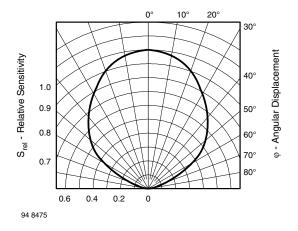
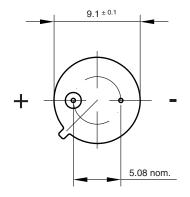
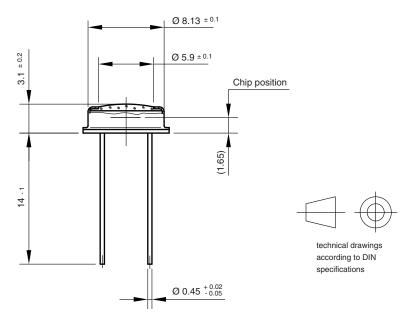


Fig. 6 - Relative Radiant Sensitivity vs. Angular Displacement



### **PACKAGE DIMENSIONS** in millimeters





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